

Description

The AR0521P0 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The AR0521P0 has an ultra-low capacitance with a typical value at 0.3pF, and complies with the IEC 61000-4-2 (ESD) standard with ±25kV air and ±22kV contact discharge. It is assembled into an ultra-small 0.6x0.3x0.3mm lead-free DFN package. The small size, ultra-low capacitance and high ESD surge protection make AR0521P0 an ideal choice to protect cell phone, digital video interfaces, HDMI, DVI, USB2.0, USB3.0, and other high speed ports.

Features

Ultra small package: 0.6x0.3x0.3mm
Ultra low capacitance: 0.3pF typical

Ultra low leakage: nA level

Operating voltage: 5V

Low clamping voltage

• 2-pin leadless package

Complies with following standards:

IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±25kV

Contact discharge: ±22kV

- IEC61000-4-5 (Lightning) 4A (8/20µs)

Mechanical Characteristics

Package: DFN0603-2 (0.6×0.3×0.3mm)

Case Material: "Green" Molding Compound.

• Moisture Sensitivity: Level 3 per J-STD-020

Terminal Connections: See Diagram Below

Marking Information: See Below

Applications

Cellular Handsets and Accessories

Display Ports

MDDI Ports

USB Ports

Digital Visual Interface (DVI)

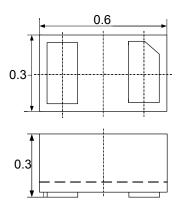
PCI Express and Serial SATA Ports

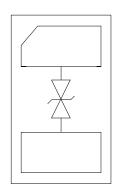
Marking Information

ZZ

Dimensions and Pin Configuration

RoHS Compliant





Package Dimensions Circuit and Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size	
AR0521P0	10000/Tape & Reel	7 inch	



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

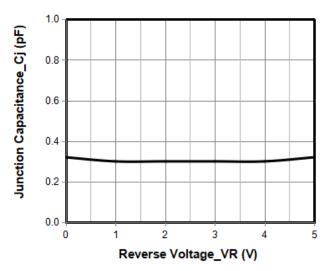
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	100	W	
Peak Pulse Current (8/20µs)	IPP	4	Α	
ESD per IEC 61000-4-2 (Air)	\/50D	±25	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±22		
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

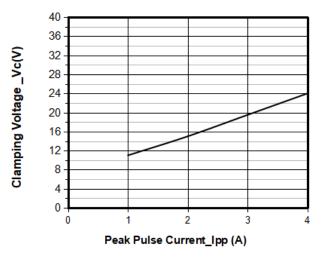
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6.5		9.5	V	IT = 1mA
Reverse Leakage Current	I _R		0.02	0.2	μA	VRWM = 5V
Clamping Voltage	Vc			12	V	IPP = 1A (8 x 20μs pulse)
Clamping Voltage	Vc			25	V	IPP = 4A (8 x 20µs pulse)
Junction Capacitance	Cı		0.3	0.5	pF	VR = 0V, f = 1MHz



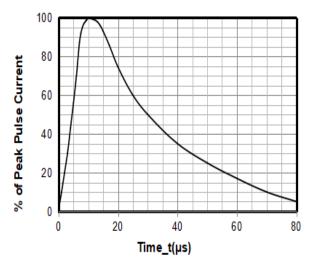
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



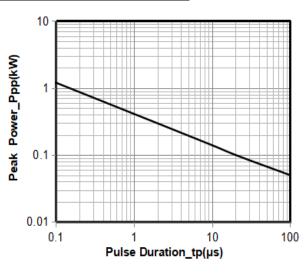
Junction Capacitance vs. Reverse Voltage



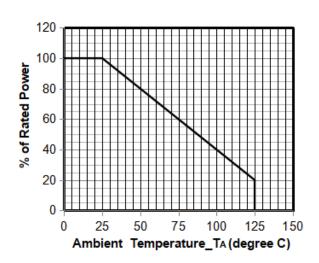
Clamping Voltage vs. Peak Pulse Current



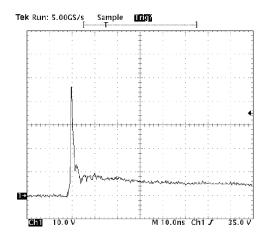
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



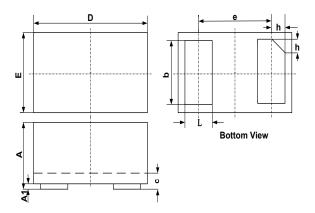
Power Derating Curve



ESD Clamping Voltage 8 kV Contact per IEC61000-4-2

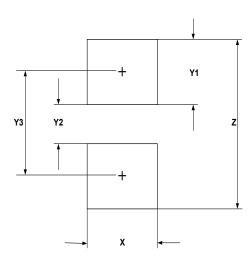


DFN0603-2 Package Outline Drawing



	DIMENSIONS			
	MILLIMETERS			
SYM	MIN	NOM		MAX
Α	0.230			0.330
A1	0.000	0.020		0.050
b	0.215	0.245		0.275
С	0.120	0.150		0.180
D	0.550	0.600		0.650
е	0.355 BSC			
Е	0.250	0.300		0.350
L	0.160	0.190		0.220
h	0.079 BSC			

Suggested Land Pattern



CVM	DIMENSIONS				
SYM	MILLIMETERS	INCHES			
Х	0.30	0.012			
Y1	0.25	0.010			
Y2	0.15	0.006			
Y3	0.40	0.016			
Z	0.65	0.026			

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